

MSK 100 VOLT 10 AMP RAD-HARD H-BRIDGE PWM MOTOR DRIVER/AMPLIFIER 4204RH

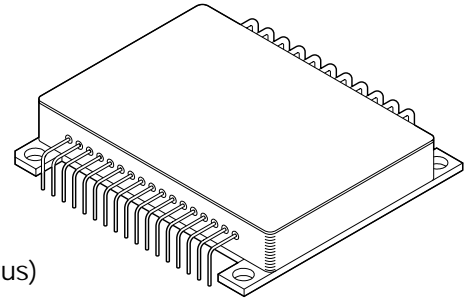
M.S.KENNEDY CORP. DRIVER/AMPLIFIER

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FEATURES:

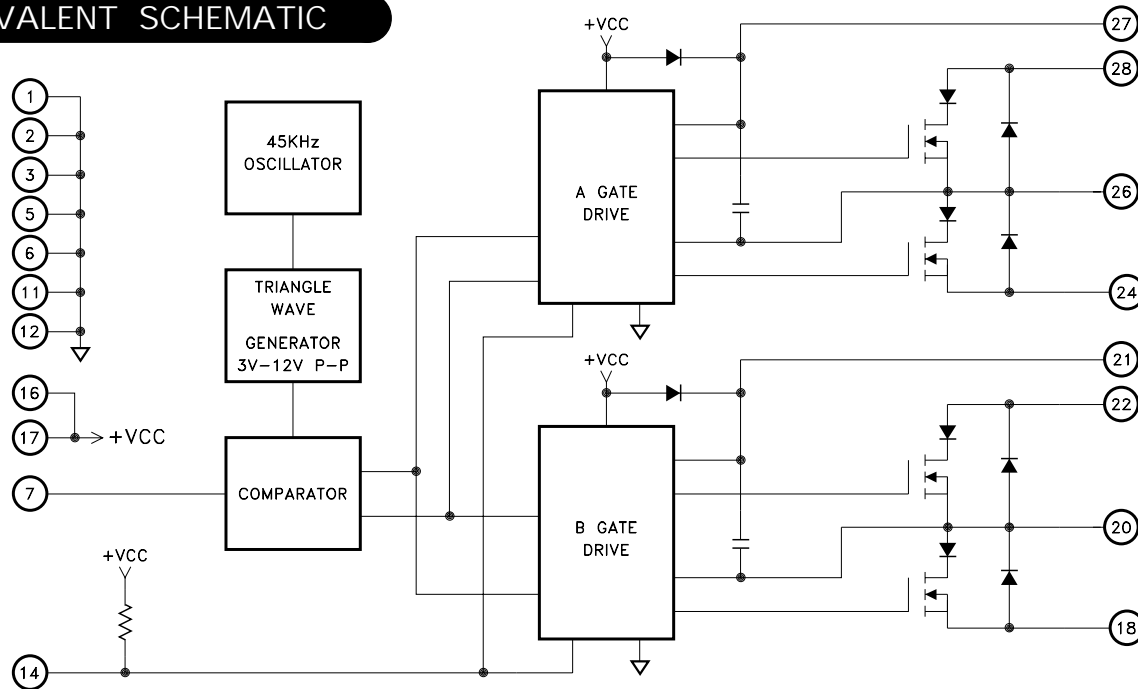
- Total Dose Tested To TBDK RAD (Method 1019.7 Condition A)
- 100 Volt, 10 Amp Capability
- Self-Contained Smart Lowside/Highside Drive Circuitry
- Internal PWM Generation, Shoot-through Protection
- Isolated Case Allows Direct Heatsinking
- Available Fully Screened To MIL-PRF-38534 Class K and Class H
- Output Stage Includes Blocking and Reverse Diodes
- Contact MSK for MIL-PRF-38534 Qualification and Appendix G (Radiation Status)



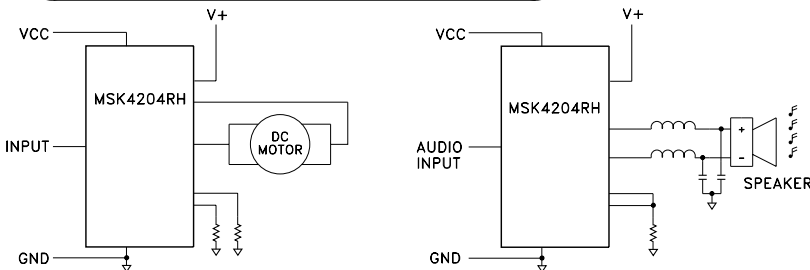
DESCRIPTION:

The MSK 4204RH is a radiation hardened complete H-Bridge microcircuit intended for use in DC brushed motor control applications or Class D switchmode amplification in space or other severe operating environments. The internal components have been selected to provide total dose up to 300K RAD for military and space applications. All of the drive/control circuitry for the lowside and highside switches are internal to the device. The PWM circuitry is internal as well, leaving the user to only provide an analog signal for the motor speed/direction, or audio signal for switchmode audio amplification. If 100% duty cycle is required, access to the high-side bias has been provided. With the addition of two isolated power supplies 100% duty cycle is possible. The MSK 4204RH is packaged in a space efficient isolated power package, available in three lead form configurations that can be directly connected to a heatsink.

EQUIVALENT SCHEMATIC



TYPICAL APPLICATIONS



PIN-OUT INFORMATION

1 GND	8 NC	15 NC	22 BV+
2 GND	9 NC	16 +VCC	23 NC
3 GND	10 NC	17 +VCC	24 AV-
4 NC	11 GND	18 BV-	25 NC
5 GND	12 GND	19 NC	26 AØ
6 GND	13 NC	20 BØ	27 AVB
7 INPUT	14 SHUTDOWN	21 BVB	28 AV+

ABSOLUTE MAXIMUM RATINGS ^⑦

V+	High Voltage Supply	100V
V _{CC}	Logic Supply	20V
I _{OUT}	Continuous Output Current	10A
I _{PK}	Peak Output Current	20A
V _{OUT}	Output Voltage Range	GND-5V min. to V+ max.
V _{IN}	Input Voltage	V _{CC}
V _L	Logic Input Voltage (Shutdown)	0V to V _{CC}
V _B	High-Side Bias	20V

T _{ST}	Storage Temperature Range	-65° C to + 150° C
T _{LD}	Lead Temperature Range (10 Seconds)	300° C
T _C	Case Operating Temperature	-55° C to + 125° C
T _J	Junction Temperature	+ 150° C
θ _{JC}	Thermal Resistance (Output FETS @ 125° C)	2.5° C/W
	(Output Diodes @ 125° C)	3.2° C/W

ELECTRICAL SPECIFICATIONS

Parameter	Test Conditions ^①	Group A Subgroup ^④	MSK 4204RH ^③			Units
			Min.	Typ.	Max.	
OUTPUT CHARACTERISTICS						
V _{DS(ON)} Voltage (Diode plus MOSFET)	ID = 10A	1	-	TBD	TBD	V
	ID = 8.6A	2	-	TBD	TBD	V
	ID = 10A	3	-	TBD	TBD	V
Instantaneous Forward Voltage	IS = 10A	1	-	TBD	TBD	V
		2	-	TBD	TBD	V
		3	-	TBD	TBD	V
R _{DS(ON)} each MOSFET ^② ^⑥	ID = 10A TC = 25° C	-	-	0.06	0.1	Ω
Leakage Current, each MOSFET ^②	V+ = 80V	1	-	1	25	uA
		2	-	10	250	uA
		3	-	1	25	uA
PWM Frequency		4,5,6	40	45	50	KHz
VCC SUPPLY CHARACTERISTICS						
Quiescent Current	V _{IN} = 7.5V	1,2,3	-	TBD	TBD	mA
UVLO	V _{CC} Increasing	1	7.5	TBD	9.7	V
	V _{CC} Decreasing	1	7.0	TBD	9.4	V
OUTPUT DUTY CYCLE						
	V _{IN} = 7.5V Both Outputs Tested	4,5,6	40	50	60	%
	V _{IN} = 15V Output A = 100% Duty Cycle High Output B = 0% Duty Cycle Low	7	-	Verify	-	P/F
	V _{IN} = 0V Output A = 0% Duty Cycle Low Output B = 100% Duty Cycle High	7	-	Verify	-	P/F
SWITCHING CHARACTERISTICS						
Rise Time ^②	RL = 1K A to B	4	-	20	100	nS
Fall Time ^②	RL = 1k A to B	4	-	20	100	nS
LOGIC CONTROL INPUTS						
Shutdown Input	Input Voltage LO	1,2,3	-	-	5.7	V
	Input Voltage HI	1,2,3	10.0	-	-	V
	Input Current (Low) V _{IN} = 0V	1,2,3	-	1.0	1.3	mA
	Input Current (High) V _{IN} = +V _{CC}	1,2,3	-	TBD	100	uA

NOTES:

- ① V_{CC} = 15V, V+ = 28V, AV-, BV- = Ground, Shutdown = 0V unless otherwise specified.
- ② Guaranteed by design but not tested. Typical parameters are representative of actual device performance but are for reference only.
- ③ Devices shall be 100% tested to subgroups 1,2,3,4, and 7. Subgroup 5 and 6 testing available upon request.
- ④ Subgroup 1,4,7 TA = TC = + 25° C
2,5 TA = TC = + 125° C
3,6 TA = TC = -55° C
- ⑤ Industrial grade and "E" suffix devices shall be 100% tested at 25° C only.
- ⑥ The internal on resistance is for the die only. This should be used for thermal calculations only.
- ⑦ Continuous operation at or above absolute maximum ratings may adversely effect the device performance and/or life cycle.
- ⑧ Pre and post irradiation limits @ 25° C, up to TBD Krad, are identical unless otherwise specified.

MSK 4204RH PIN DESCRIPTIONS

+ VCC - Is the low voltage supply for powering internal logic and drivers for the lowside and highside MOSFETS. The supplies for the highside drivers are derived from this voltage. Optimum operation occurs with Vcc set at 15V.

AV+ , BV+ - Are the high voltage H-bridge supply pins. The MOSFETS obtain the drive current from these supply pins. The MOSFETS are rated at 100 volts. Proper bypassing to GND with sufficient capacitance to suppress any voltage transients, and ensure removal of any drooping during switching, should be done as close to the pins on the hybrid as possible.

AØ - Are the output pins for one half of the bridge. Increasing the input voltage causes increasing duty cycles at this output.

BØ - Are the output pins for the other half of the bridge. Decreasing the input voltage causes increasing duty cycles at this output.

AVB & BVB - Are the high-side bias pins. Some applications require that the high-side be on for an indefinite period of time. Under these conditions the charge in the boost capacitor will not be adequate to keep the high-side output on. If continuous on time is required, external floating power supplies must be connected to the AVB and BVB pins to power the high-side drive. Blocking diodes should be used to prevent Vcc from sourcing current to the floating supply should Vcc rise above the floating supply level. Reference typical system operation schematic. If not used, the high-side bias pins must remain high impedance.

AV- - Are the connections for the bottom of the A half bridge. This can have a sense resistor connection to the V+ return ground for current limit sensing, or can be connected directly to ground. The maximum voltage on these pins is ± 5 volts with respect to GND.

BV- - Are the connections for the bottom of the B half bridge. This can have a sense resistor connection to the V+ return ground for current limit sensing, or can be connected directly to ground. The maximum voltage on these pins is ± 5 volts with respect to GND.

GND - Is the return connection for the input logic and Vcc.

INPUT - Is an analog input for controlling the PWM pulse width of the bridge. A voltage higher than 7.5V will produce greater than 50% duty cycle pulses out of OUTPUT A. A voltage lower than 7.5V will produce greater than 50% duty cycle pulses out of OUTPUT B.

SHUTDOWN - Is the connection for disabling all 4 output switches. SHUTDOWN high overrides all other inputs. When taken low, everything functions normally. An internal pullup to Vcc will keep SHUTDOWN high if left unconnected. This pin should be grounded if not used.

UVLO - The under voltage lockout function of the MSK 4204RH prevents the device from starting before sufficient bias voltage is available. The UVLO feature monitors the VCC supply and holds the outputs low until the voltage level rises above the threshold during start up. After start up the low side UVLO circuit will hold the low side switches off if VCC falls below the threshold. The high side UVLO circuit will hold the high side switches off any time the voltage on the bootstrap capacitor falls below the threshold.

MAXIMUM DUTY CYCLE AND HIGH SIDE BIAS - The MSK 4204RH uses two independent bootstrap circuits to power each of the high side switches. When the switches are turned on the high side drivers are powered by the charge in the bootstrap capacitors. The voltage on the bootstrap capacitors has an initial TBD V drop and decays at a rate of approximately TBD V every 100uS. The voltage can be approximated by the equation:

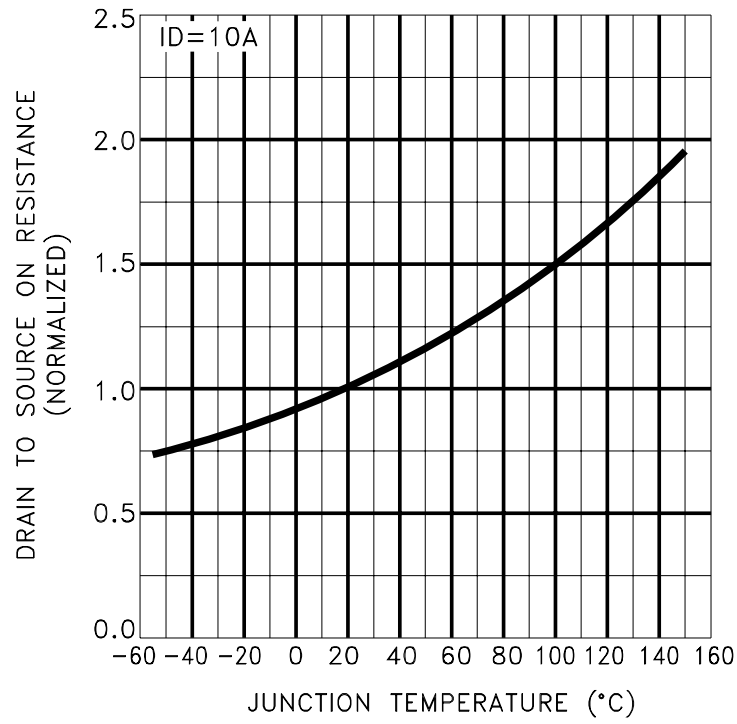
$$V_{BS} = + V_{CC} - \text{TBD V} - \text{TBD} \times T_{ON}$$

TON is the switch on time in mS
VBS is the bootstrap capacitor voltage

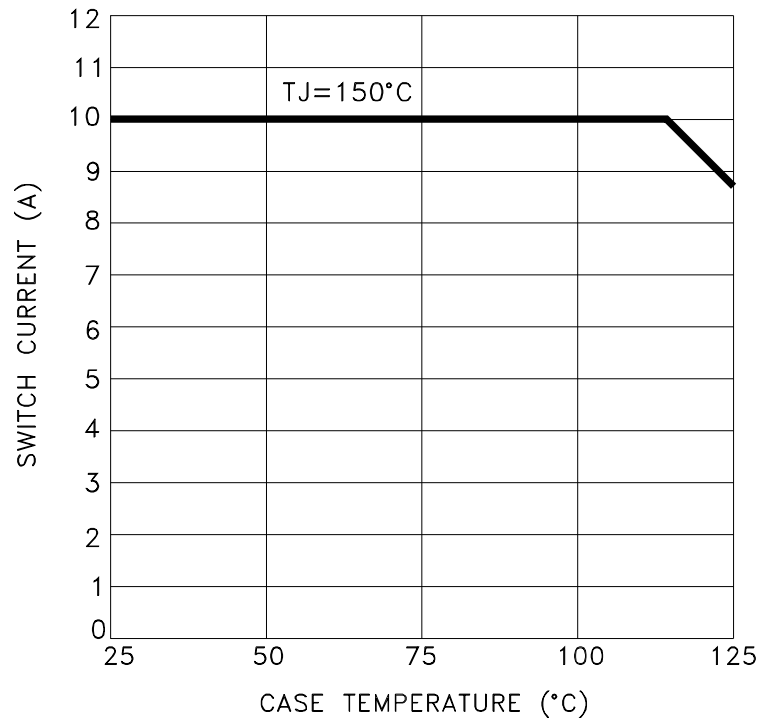
VBS should be greater or equal to 10 volts to ensure that VBS does not drop below the UVLO threshold.

The lowside switches must be activated every cycle or held active during static operation to provide a return path for charging the highside bootstrap capacitor. If longer periods of time are required between lowside switch cycles additional capacitance can be added to the highside bias pins (AVB and BVB) to prevent VBS from falling below 10V. Should continuous on time be required external floating power supplies must be used.

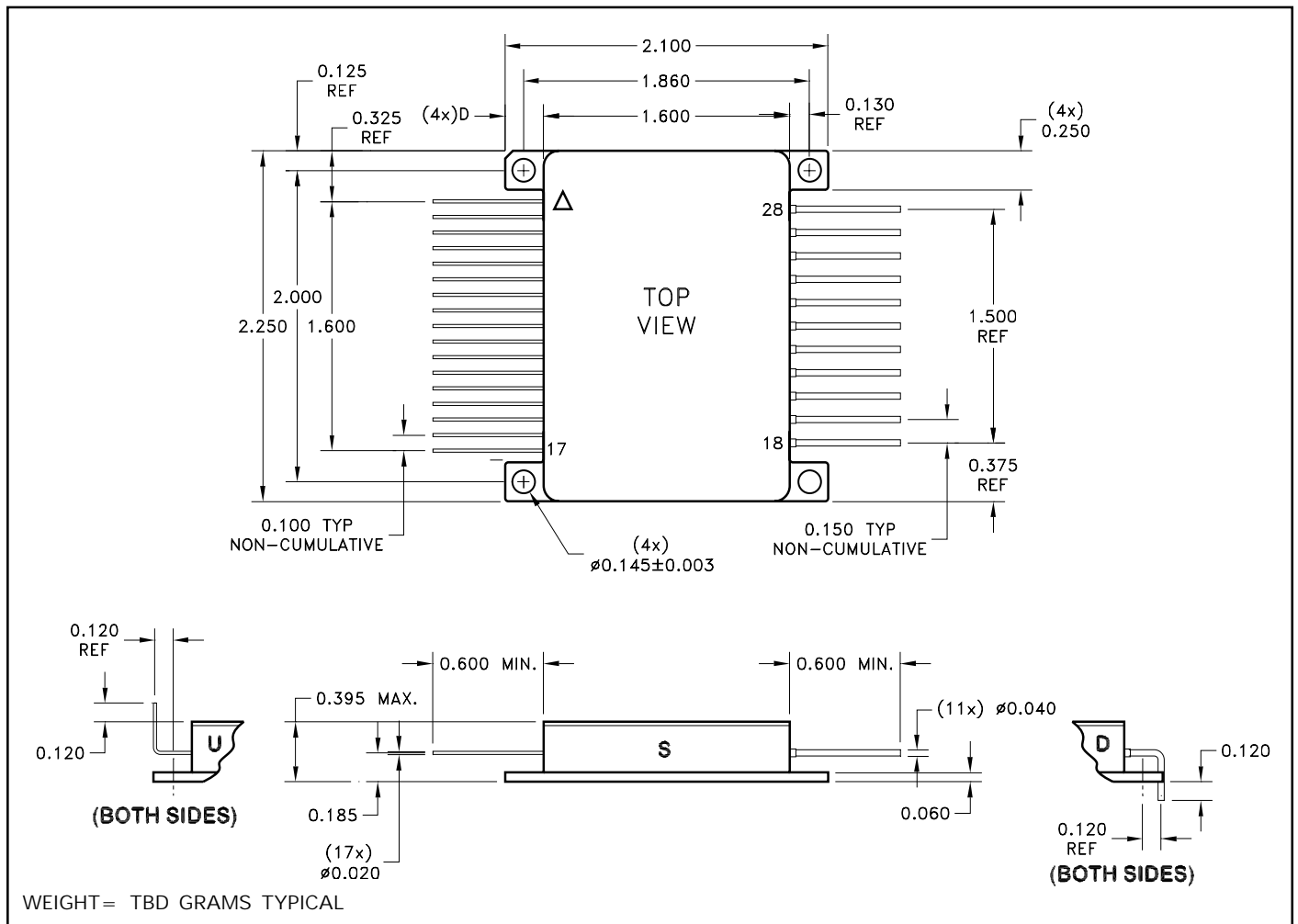
RADIATION PERFORMANCE CURVES



SAFE OPERATING AREA
SWITCH CURRENT vs CASE TEMPERATURE



MECHANICAL SPECIFICATIONS



ORDERING INFORMATION

MSK4204 H RH U

LEAD CONFIGURATIONS
 S=STRAIGHT; U= BENT UP; D= BENT DOWN

RADIATION HARDENED
 SCREENING

BLANK= INDUSTRIAL; E= EXTENDED RELIABILITY

H= MIL-PRF-38534 CLASS H; K= MIL-PRF-38534 CLASS K

GENERAL PART NUMBER

The above example is a Military grade class H hybrid with leads bent up.

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Please visit our website for the most recent revision of this datasheet.

Contact MSK for MIL-PRF-38534 Class H, Class K and Appendix G (radiation) status.